

#### NCE N-Channel Enhancement Mode Power MOSFET

### **Description**

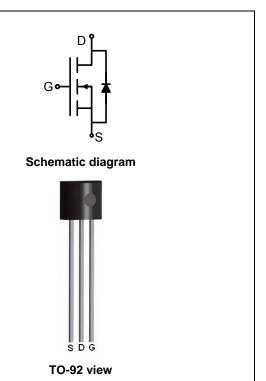
The NCE0102Z uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

- $V_{DS}$  = 100V, $I_D$  = 2A  $R_{DS(ON)}$  <240mΩ @  $V_{GS}$ =10V (Typ:210mΩ)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

#### **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



## **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
0102Z	NCE0102Z	TO-92	-	-	-

Absolute Maximum Ratings (T<sub>A</sub>=25 ℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	2	Α
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	5	Α
Maximum Power Dissipation	P <sub>D</sub>	1.25	W
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	$^{\circ}$ C

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	100	°C/W

#### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	100	110	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA



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# NCE0102Z

Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}$ =±20 $V$ , $V_{DS}$ =0 $V$	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.2	1.8	2.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =1A	-	210	240	mΩ
Forward Transconductance	ince $g_{FS}$ $V_{DS}=5V,I_D=1A$		1	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ -50\/\/ -0\/	-	190	-	PF
Output Capacitance	C <sub>oss</sub>	- V <sub>DS</sub> =50V,V <sub>GS</sub> =0V, - F=1.0MHz	-	22	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UIVITZ	-	13	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	6	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =50V, $I_{D}$ =1.3A, $R_{L}$ =39 $\Omega$	-	10	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =1 $\Omega$	-	10	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	6	-	nS
Total Gate Charge	Qg	V -50VI -4.2A	-	5.2		nC
Gate-Source Charge	$Q_{gs}$	$V_{DS}$ =50V, $I_{D}$ =1.3A, $V_{GS}$ =10V	-	0.75	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> -10V	-	1.4	-	nC
Drain-Source Diode Characteristics	<u>.</u>			•		
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =1.3A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	2	Α

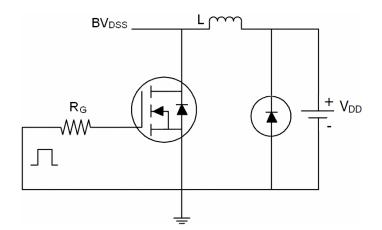
## Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- $\textbf{4.} \ \textbf{Guaranteed by design}, \ \textbf{not subject to production}$

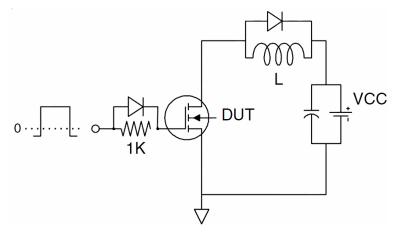


## **Test Circuit**

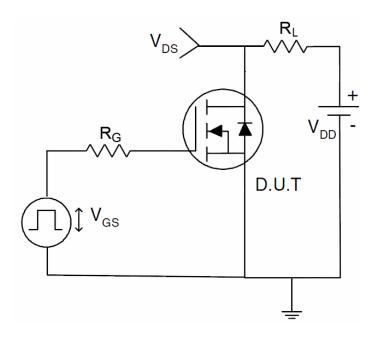
## 1) E<sub>AS</sub> test circuit



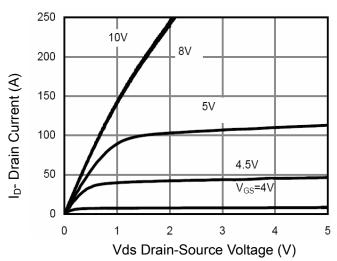
## 2) Gate charge test circuit



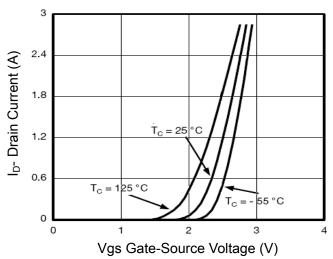
## 3) Switch Time Test Circuit



## Typical Electrical and Thermal Characteristics (Curves)



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

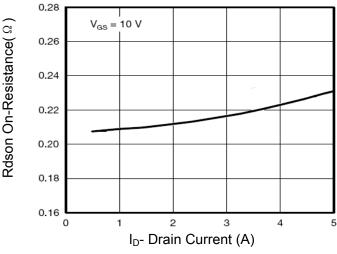


Figure 3 Rdson- Drain Current

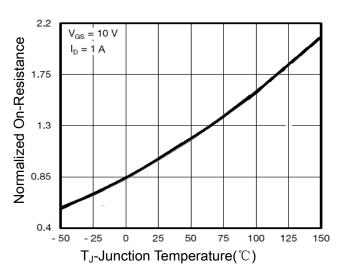


Figure 4 Rdson-JunctionTemperature

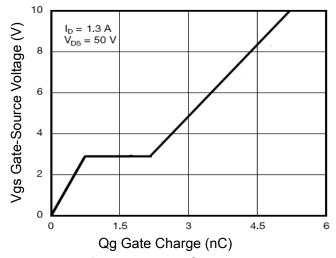


Figure 5 Gate Charge

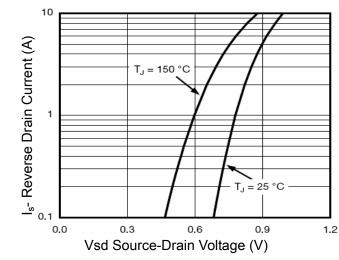


Figure 6 Source- Drain Diode Forward

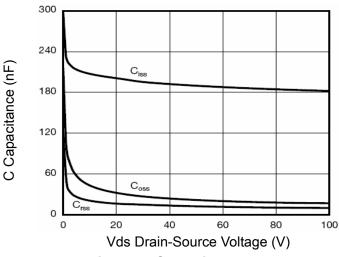


Figure 7 Capacitance vs Vds

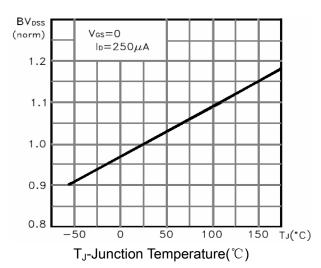
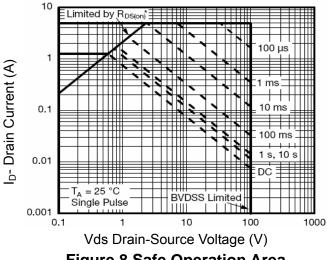


Figure 9 BV<sub>DSS</sub> vs Junction Temperature



**Figure 8 Safe Operation Area** 

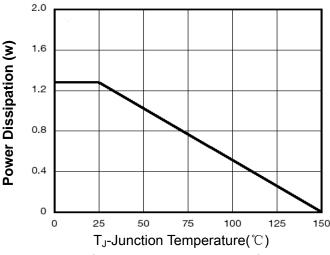
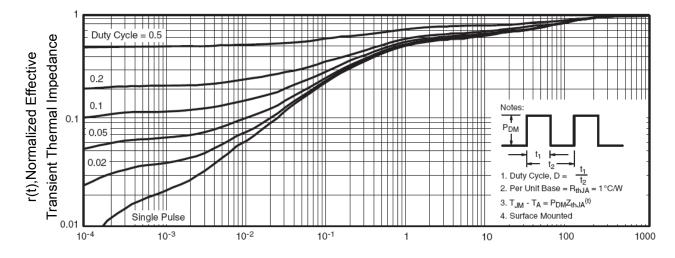


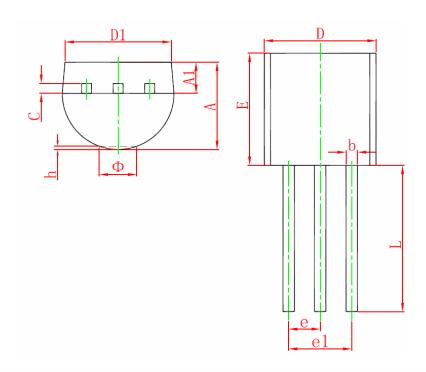
Figure 10 Power De-rating



Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance

# **TO-92 Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
Α	3.300	3.700	0.130	0.146		
A1	1.100	1.400	0.043	0.055		
b	0.380	0.550	0.015	0.022		
С	0.360	0.510	0.014	0.020		
D	4.400	4.700	0.173	0.185		
D1	3.430		0.135			
E	4.300	4.700	0.169	0.185		
е	1.270	TYP	0.050	TYP		
e1	2.440	2.640	0.096	0.104		
L	14.100	14.500	0.555	0.571		
Ф		1.600		0.063		
h	0.000	0.380	0.000	0.015		

#### **Notes**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$

**Pb-Free Product** 



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